Low-power Schmitt trigger Rev. 1 — 13 July 2021

1. General description

The 74AUP1G17-Q100 is a single buffer with Schmitt-trigger input. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
 - Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 Class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 Class C3 exceeds 1000 V
 - MM: JESD22-A115-A exceeds 200 V

3. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
74AUP1G17GW-Q100	-40 ° C to +125 ° C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					

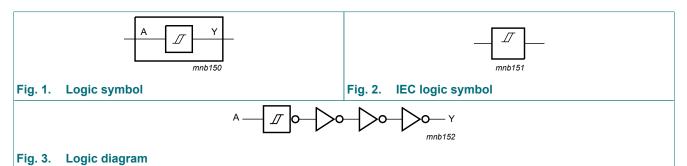
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4. Marking

Table 2. Marking						
	Type number	Marking code[1]				
	74AUP1G17GW-Q100	۲q				

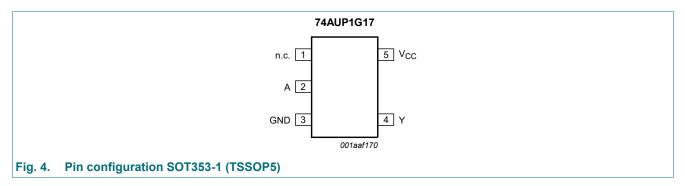
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description								
Symbol	Pin	Description						
n.c.	1	not connected						
A	2	data input						
GND	3	ground (0 V)						
Y	4	data output						
V _{CC}	5	supply voltage						

Table 2 Din description

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7. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output
A	Y
L	L
Н	Н

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1	-0.5	+4.6	V
lo	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	+50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$ [2]	-	250	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

9. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 25	5 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+} \text{ or } V_{T-}$				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A}; \\ V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μA
CI	input capacitance	V_I = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_0 = GND; V_{CC} = 0 V$	-	1.7	-	pF

Low-power Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	10 °C to +85 °C					-
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
lį –	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
∆I _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	50	μA

Low-power Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	10 °C to +125 °C	,				1
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
∆I _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μA

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 6

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Мах	Min	Max	
C _L = 5 p	F	1					1		-	
t _{pd}	propagation	A to Y; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	19.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	5.7	10.6	2.5	10.9	2.5	11.1	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.2	6.5	2.3	7.1	2.3	7.4	ns
		V _{CC} = 1.65 V to 1.95 V	2.0	3.6	5.5	1.9	6.1	1.9	6.3	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.0	4.2	1.8	4.6	1.8	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	2.7	3.6	1.5	3.8	1.5	4.0	ns
C _L = 10	pF									
t _{pd}	propagation	A to Y; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	22.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.9	6.6	12.4	2.7	12.9	2.7	13.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.6	4.8	7.8	2.4	8.3	2.4	8.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.2	6.3	2.4	6.8	2.4	7.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	3.5	4.8	2.1	5.3	2.1	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	3.3	4.4	2.0	4.6	2.0	4.8	ns
C _L = 15	pF									
t _{pd}	propagation	A to Y; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	26.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.4	14.1	3.1	14.7	3.1	14.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.1	5.4	8.7	2.8	9.5	2.8	9.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.7	4.7	7.1	2.7	7.8	2.7	8.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.6	4.0	5.6	2.5	6.0	2.5	6.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.7	4.9	2.2	5.2	2.2	5.5	ns
C _L = 30	pF									
t _{pd}	propagation	A to Y; see <u>Fig. 5</u> [2]								
	delay	V _{CC} = 0.8 V	-	36.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.9	9.7	19.0	3.7	19.8	3.7	20.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.5	7.0	11.2	3.6	12.4	3.6	13.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.5	6.0	9.2	3.4	10.1	3.4	10.7	ns
		V _{CC} = 2.3 V to 2.7 V	3.4	5.1	7.0	3.2	7.5	3.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	4.8	6.2	3.1	7.1	3.1	7.5	ns

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Low-power Schmitt trigger

Symbol	Parameter	Conditions	25 °C		25 °C -40 °C to +85 °C		-40 °C to	+125 °C	Unit	
			Min	Typ[1]	Мах	Min	Max	Min	Мах	1
C _L = 5 p	F, 10 pF, 15 pF	and 30 pF								
C _{PD}	power	f = 1 MHz; V_I = GND to V_{CC} [3]								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.5	-	-	-	-	-	pF
	capacitance	V _{CC} = 1.1 V to 1.3 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.5	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.0	-	-	-	-	-	pF

[1] All typical values are measured at nominal V_{CC} .

[2] t_{pd} is the same as t_{PLH} and t_{PHL}

[3] \dot{C}_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

11.1. Waveform and test circuit

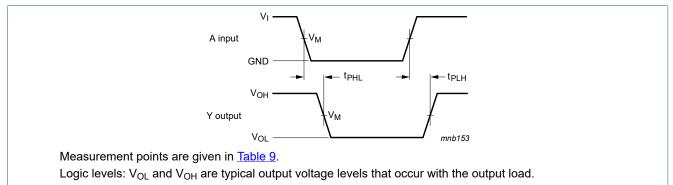


Fig. 5. The data input (A) to output (Y) propagation delays

Table 9. Measurement points

Supply voltage	Output	Input					
V _{cc}	V _M	V_M V_i $t_r = t_f$					
0.8 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns			

Low-power Schmitt trigger

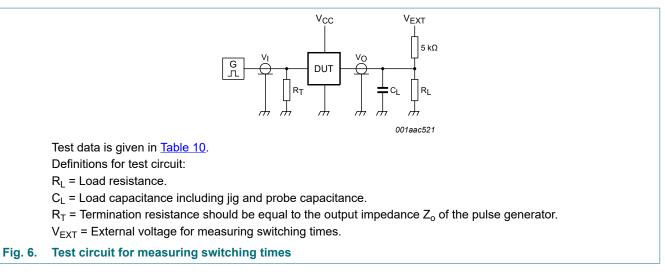


Table 10. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 x V _{CC}

[1] For measuring enable and disable times, $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

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12. Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V).

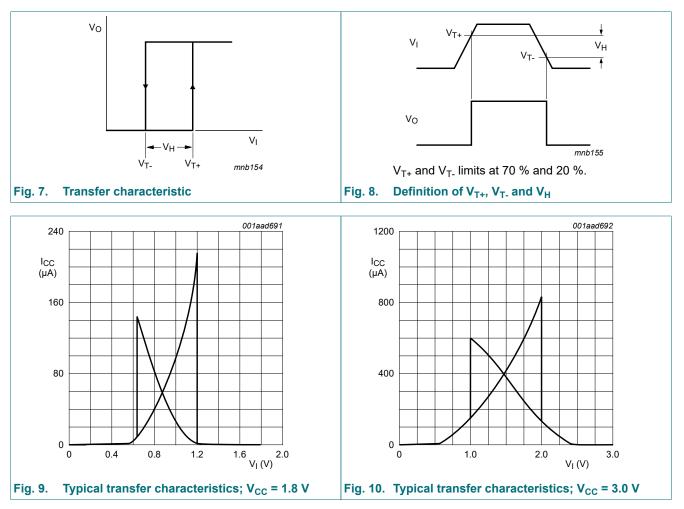
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	5 °C	-	_			
V _{T+}	positive-going threshold	see <u>Fig. 7</u> and <u>Fig. 8</u>				
	voltage	V _{CC} = 0.8 V	0.30	-	0.60	V
		V _{CC} = 1.1 V	0.53	-	0.90	V
		V _{CC} = 1.4 V	0.74	-	1.11	V
		V _{CC} = 1.65 V	0.91	-	1.29	V
		V _{CC} = 2.3 V	1.37	-	1.77	V
		V _{CC} = 3.0 V	1.88	-	2.29	V
	negative-going threshold voltage	see <u>Fig. 7</u> and <u>Fig. 8</u>				
		V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H hyst	hysteresis voltage	see <u>Fig. 7, Fig. 8, Fig. 9</u> and <u>Fig. 10</u>				
		V _{CC} = 0.8 V	0.07	-	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	V

Low-power Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +85 °C	-				
V _{T+}	positive-going threshold	see <u>Fig. 7</u> and <u>Fig. 8</u>				
	voltage	V _{CC} = 0.8 V	0.30	-	0.60	V
		V _{CC} = 1.1 V	0.53	-	0.90	V
		V _{CC} = 1.4 V	0.74	-	1.11	V
		V _{CC} = 1.65 V	0.91	-	1.29	V
		V _{CC} = 2.3 V	1.37	-	1.77	V
		V _{CC} = 3.0 V	1.88	-	2.29	V
V _{T-}	negative-going threshold	see <u>Fig. 7</u> and <u>Fig. 8</u>				
	voltage	V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H	hysteresis voltage	see <u>Fig. 7, Fig. 8, Fig. 9</u> and <u>Fig. 10</u>				
		V _{CC} = 0.8 V	0.07	-	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	V
T _{amb} = -4	40 °C to +125 °C					
V _{T+} positive-goin voltage	positive-going threshold	see <u>Fig. 7</u> and <u>Fig. 8</u>				
	voltage	V _{CC} = 0.8 V	0.30	-	0.62	V
		V _{CC} = 1.1 V	0.53	-	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.32	V
V _{T-} negative-going threshold voltage	negative-going threshold	see <u>Fig. 7</u> and <u>Fig. 8</u>				
	voltage	V _{CC} = 0.8 V	0.10	-	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	V
V _H	hysteresis voltage	see <u>Fig. 7, Fig. 8, Fig. 9</u> and <u>Fig. 10</u>				
	-	V _{CC} = 0.8 V	0.07	-	0.50	V
		$V_{CC} = 1.1 V$	0.08	-	0.46	V
		$V_{CC} = 1.4 V$	0.18	-	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	V
		V _{CC} = 3.0 V	0.79		1.31	V

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Low-power Schmitt trigger



12.1. Waveforms transfer characteristics

13. Application information

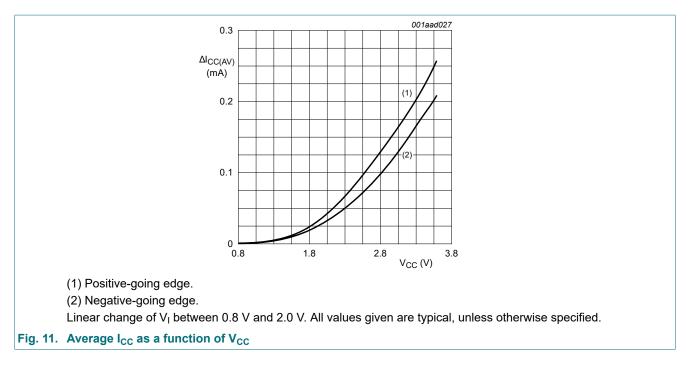
The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{ad} = f_i x (t_r x I_{CC(AV)} + t_f x I_{CC(AV)}) x V_{CC}$ where:

- P_{ad} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- I_{CC(AV)} = average additional supply current (μA).

Average I_{CC} differs with positive or negative input transitions, as shown in Fig. 11.

Low-power Schmitt trigger



Low-power Schmitt trigger

14. Package outline

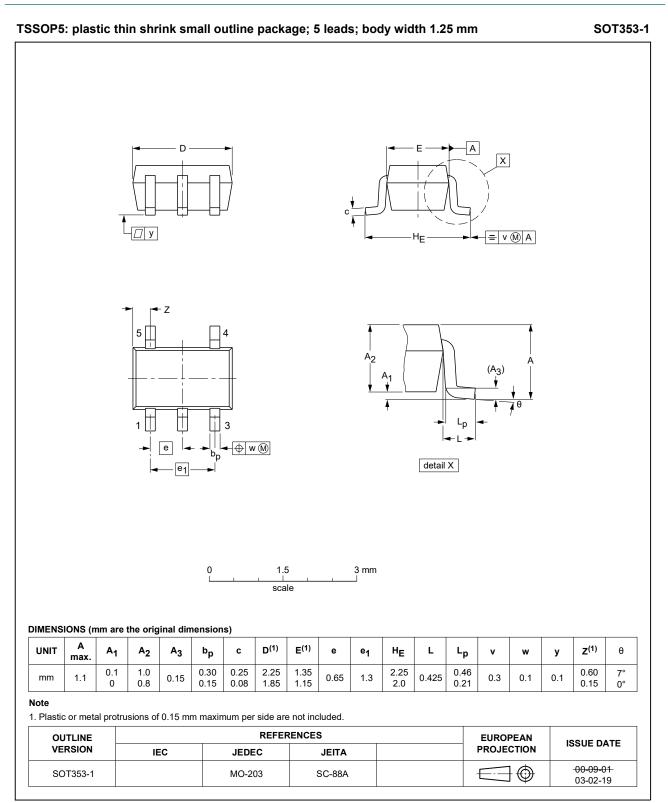


Fig. 12. Package outline SOT353-1 (TSSOP5)

15. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

16. Revision history

	Table 13	. Revision	history
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Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G17_Q100 v.1	20210713	Product data sheet	-	-

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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